TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74AC166P, TC74AC166F, TC74AC166FN

## 8 - BIT SHIFT REGISTER (P - IN, S - OUT)

The TC74AC166 is an advanced high speed CMOS 8-BIT PARALLEL/SERIAL-IN, SERIAL-OUT SHIFT REGISTER fabricated with silicon gate and double-layer metal wiring  $C^2MOS$  technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

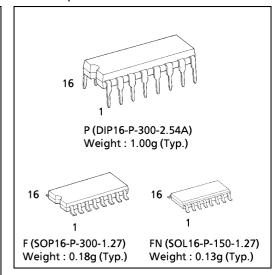
It consists of parallel-in or serial-in, serial-out 8 - bit shift register with a gated clock input and an overriding clear input. The parallel-in or serial-in modes are controlled by the SHIFT/LOAD input. When the SHIFT/LOAD input is held high, the serial data input is enabled and the eight flip-flops perform serial shifting on each clock pulse. When held low, the parallel data inputs are enabled and synchronous loading occurs on the next clock pulse. Clocking is accomplished on the low-to-high transition of the clock pulse. The CLOCK-INHIBIT input should be shifted high only while the CLOCK input is held high. A direct clear input overrides all other inputs, including the clock, and sets all the flip-flops to zero. Functional details are shown in the truth table and the timing charts.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

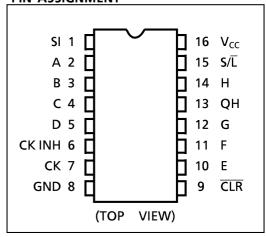
#### FEATURES:

- High Noise Immunity V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (Min.)
   Symmetrical Output Impedance | I<sub>OH</sub> | = I<sub>OL</sub> = 24mA(Min.)
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 24\text{mA}(\text{Min.})$ Capability of driving  $50\Omega$ transmission lines.
- Balanced Propagation Delays  $\cdots t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range ···· V<sub>CC</sub> (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74HC166

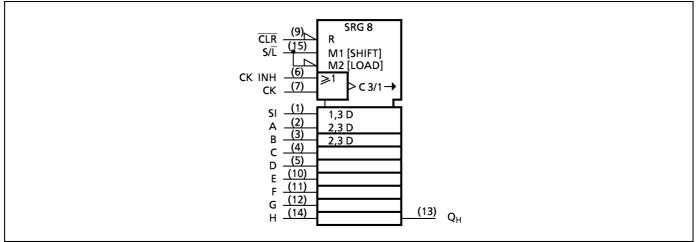
(Note) The JEDEC SOP (FN) is not available in Japan.



# PIN ASSIGNMENT



## **IEC LOGIC SYMBOL**



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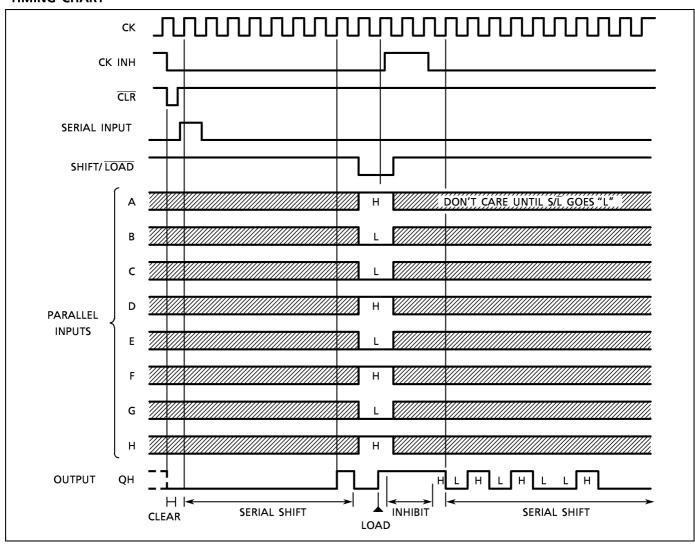
# TRUTH TABLE

		INTERNAL	OUTPUT				
CLR	SHIFT/ LOAD	CK INH.	CK	SERIAL IN	PARALLEL A ······ H	QA QB	QH
L	Х	Х	Х	Х	Х	L L	L
Н	Х	Х	7_	Х	Х	NO CH	IANGE
Н	L	L		Х	a h	a b	h
Н	Н	L		Н	Х	H QAn	QGn
Н	Н	L	<u>-</u>	L	Х	L QAn	QGn
Н	Х	Н	Х	Х	Х	NO CH	IANGE

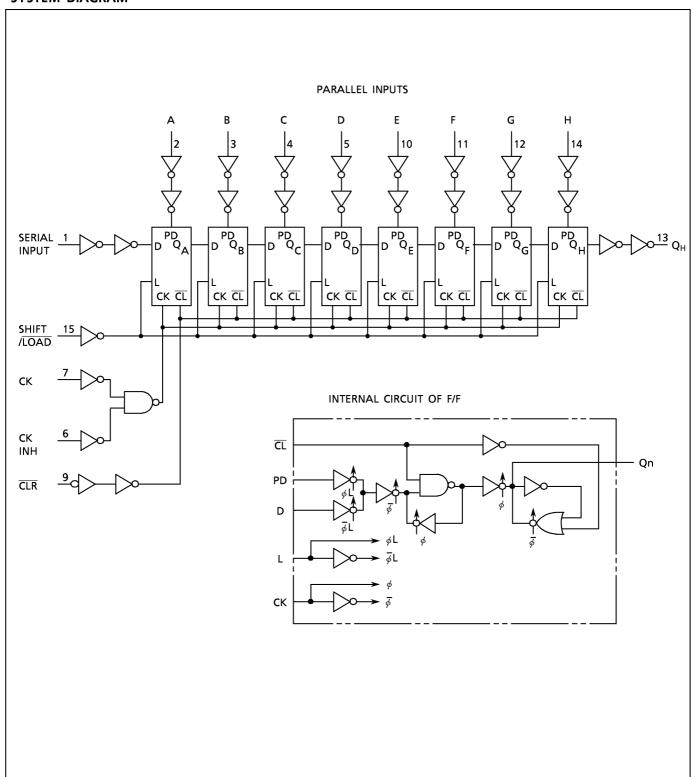
X : Don't Care

a ····· h: The level of steady state input voltage at inputs A through H respectively

#### **TIMING CHART**



## SYSTEM DIAGRAM



# **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	-0.5~7.0	٧
DC Input Voltage	V <sub>IN</sub>	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V <sub>OUT</sub>	−0.5~V <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 50	mA
DC Output Current	I <sub>OUT</sub>	± 50	mA
DC V <sub>CC</sub> /Ground Current	I <sub>cc</sub>	± 100	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	<b>−65~150</b>	°C

<sup>\*500</sup>mW in the range of Ta =  $-40^{\circ}$ C  $\sim$ 65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

#### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	VIN	0~V <sub>cc</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>cc</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	dt/dV	$0 \sim 100 \text{ (Vcc} = 3.3 \pm 0.3 \text{V)}$ $0 \sim 20 \text{ (Vcc} = 5 \pm 0.5 \text{V)}$	ns / V

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V <sub>cc</sub>	Ta = 25°C			Ta = -4	UNIT	
PARAIVIETER	STIVIBUL			(V)	MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	VIH				1.50 2.10 3.85	111		1.50 2.10 3.85	_ _ _	\ \
Low - Level Input Voltage	VIL				111	111	0.50 0.90 1.65	_ 	0.50 0.90 1.65	٧
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	_ _ _	1.9 2.9 4.4	_ _ _	,,
			$I_{OH} = -4mA$ $I_{OH} = -24mA$ $I_{OH} = -75mA*$	3.0 4.5 5.5	2.58 3.94 —		_ _ _	2.48 3.80 3.85	_ _ _	V
Low - Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 50 \mu A$	2.0 3.0 4.5	111	0.0 0.0 0.0	0.1 0.1 0.1	1 1 1	0.1 0.1 0.1	
Output Voltage			$I_{OL} = 12\text{mA}$ $I_{OL} = 24\text{mA}$ $I_{OL} = 75\text{mA*}$	3.0 4.5 5.5	111	111	0.36 0.36 —		0.44 0.44 1.65	V
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		5.5	1	ı	±0.1	_	± 1.0	
Quiescent Supply Current	I <sub>cc</sub>	$V_{IN} = V_{CC}$ or GND		5.5			8.0	_	80.0	μΑ

<sup>\* :</sup> This spec indicates the capability of driving  $50\Omega$  transmission lines. One output should be tested at a time for a 10ms maximum duration.

# TIMING REQUIREMENTS (Input $t_r = t_f = 3ns$ )

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C	Ta = −40~85°C	UNIT
PARAIVIETER	STIMBOL		V <sub>cc</sub> (V)	LIMIT	LIMIT	UNIT
Minimum Pulse Width ( CK )	t <sub>W (H)</sub> t <sub>W (L)</sub>		3.3 ± 0.3 5.0 ± 0.5	7.0 5.0	7.0 5.0	
Minimum Pulse Width (CLR)	t <sub>W(L)</sub>		3.3 ± 0.3 5.0 ± 0.5	8.0 5.0	8.0 5.0	
Minimum Set-up Time (SI, PI)	t <sub>s</sub>		3.3 ± 0.3 5.0 ± 0.5	8.0 4.0	8.0 4.0	
Minimum Set-up Time (S/L)	t <sub>s</sub>		3.3 ± 0.3 5.0 ± 0.5	7.0 4.0	7.0 4.0	ns
Minimum Hold Time (SI, PI)	t <sub>h</sub>		3.3 ± 0.3 5.0 ± 0.5	0.5 0.5	0.5 0.5	
Minimum Hold Time (S/L)	t <sub>h</sub>		3.3 ± 0.3 5.0 ± 0.5	1.0 1.0	1.0 1.0	
Minimum Removal Time (CLR)	t <sub>rem</sub>		3.3 ± 0.3 5.0 ± 0.5	4.0 1.5	4.0 1.5	

# AC ELECTRICAL CHARACTERISTICS ( $C_L$ = 50pF , $\,R_L$ = 500 $\,\Omega$ , Input $\,t_r$ = $t_f$ = 3ns )

PARAMETER	SYMBOL	TEST CONDITION		•	Ta = 25°C	:	Ta = - 4	UNIT	
PARAIVIETER	STIVIBOL		V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	MIN.	MAX.	OINIT
Propagation Delay Time (CK-QH)	t <sub>pLH</sub> t <sub>pHL</sub>		3.3 ± 0.3 5.0 ± 0.5	_	9.4 6.6	16.1 10.0	1.0 1.0	18.3 11.4	
Propagation Delay Time (CLR-QH)	t <sub>pHL</sub>		3.3 ± 0.3 5.0 ± 0.5		9.2 6.4	15.2 9.6	1.0 1.0	17.4 10.9	ns
Maximum Clock Frequency	f <sub>MAX</sub>		3.3 ± 0.3 5.0 ± 0.5		105 150	_	55 90	_	MHz
Input Capacitance	C <sub>IN</sub>			_	5	10	_	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (1)			_	67	_	_	_	

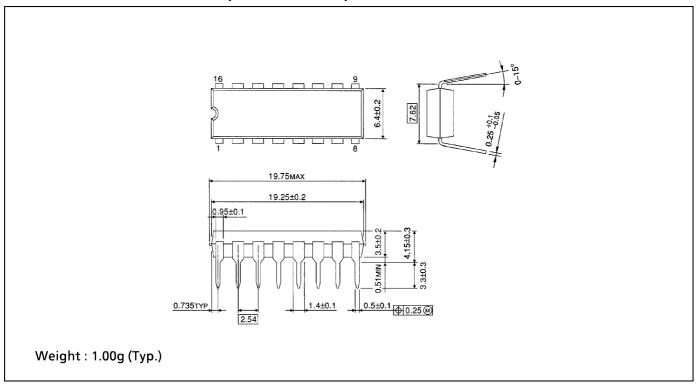
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

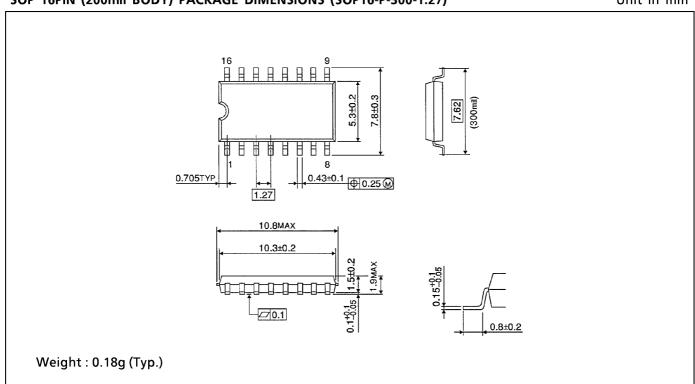
# DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



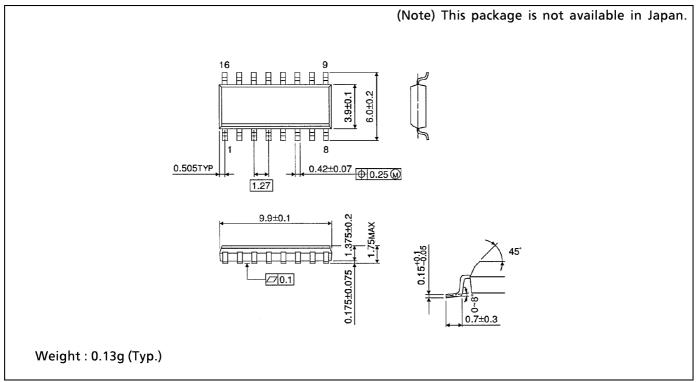
# SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



# SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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